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|--|---------------|----------------------|-------------------------|------------------|
| APPLICATION NO. | FILING DATE | FIRST NAMED INVENTOR | ATTORNEY DOCKET NO. | CONFIRMATION NO. |
| 09/779,586 | 02/09/2001 | Toshiro Hayakawa | , Q61222 | 6818 |
| 75 | 90 05/07/2003 | | | |
| SUGHRUE, MION, ZINN, MACPEAK & SEAS, PLLC 2100 Pennsylvania Avenue, N.W. Washington, DC 20037-3202 | | | EXAMINER | |
| | | | JACKSON, CORNELIUS H | |
| | | | ART UNIT | PAPER NUMBER |
| | | 2828 | | |
| • | | | DATE MAILED: 05/07/2003 | |

Please find below and/or attached an Office communication concerning this application or proceeding.

| | Application No. | Applicant(s) | | | | |
|---|--|--|--|--|--|--|
| | 09/779,586 | HAYAKAWA, TOSHIRO | | | | |
| Office Action Summary | Examiner | Art Unit | | | | |
| | Cornelius H. Jackson | 2828 | | | | |
| The MAILING DATE of this communication app Period for Reply | ears on the cover sheet with the | correspondence address | | | | |
| A SHORTENED STATUTORY PERIOD FOR REPLY THE MAILING DATE OF THIS COMMUNICATION. - Extensions of time may be available under the provisions of 37 CFR 1.13 after SIX (6) MONTHS from the mailing date of this communication. - If the period for reply specified above is less than thirty (30) days, a reply If NO period for reply is specified above, the maximum statutory period w - Failure to reply within the set or extended period for reply will, by statute, - Any reply received by the Office later than three months after the mailing earned patent term adjustment. See 37 CFR 1.704(b). Status | 36(a). In no event, however, may a reply be ting within the statutory minimum of thirty (30) day will apply and will expire SIX (6) MONTHS from a cause the application to become ABANDONE | mely filed ys will be considered timely. n the mailing date of this communication. ED (35 U.S.C. § 133). | | | | |
| 1) Responsive to communication(s) filed on <u>05 F</u> | ebruary 2003 . | | | | | |
| 2a) ☐ This action is FINAL . 2b) ☑ Th | is action is non-final. | | | | | |
| 3) Since this application is in condition for allowatelosed in accordance with the practice under Disposition of Claims | nnce except for formal matters, p Ex parte Quayle, 1935 C.D. 11, | prosecution as to the merits is 453 O.G. 213. | | | | |
| 4)⊠ Claim(s) <u>1-9 and 11-13</u> is/are pending in the a | pplication. | | | | | |
| 4a) Of the above claim(s) is/are withdraw | wn from consideration. | | | | | |
| 5) Claim(s) is/are allowed. | | Pa OSo | | | | |
| 6)⊠ Claim(s) <u>1-9 and 11-13</u> is/are rejected. | | / www. | | | | |
| 7) Claim(s) is/are objected to. | CIII | PAUL IP PERVISORY PATENT EXAMINER | | | | |
| 8) Claim(s) are subject to restriction and/o | | TECHNOLOGY CENTER 2800 | | | | |
| Application Papers | | , | | | | |
| 9)☐ The specification is objected to by the Examine | | | | | | |
| 10) ☐ The drawing(s) filed on is/are: a) ☐ accept | | | | | | |
| Applicant may not request that any objection to the | | | | | | |
| 11)☐ The proposed drawing correction filed on is: a)☐ approved b)☐ disapproved by the Examiner. | | | | | | |
| If approved, corrected drawings are required in re | - | | | | | |
| 12) ☐ The oath or declaration is objected to by the Ex | aminer. | | | | | |
| Priority under 35 U.S.C. §§ 119 and 120 | | | | | | |
| 13)☐ Acknowledgment is made of a claim for foreign | n priority under 35 U.S.C. § 119(| a)-(d) or (f). | | | | |
| a) ☐ All b) ☐ Some * c) ☐ None of: | | | | | | |
| 1. Certified copies of the priority documents have been received. | | | | | | |
| 2. Certified copies of the priority document | s have been received in Applica | tion No | | | | |
| 3. Copies of the certified copies of the prio application from the International Bu* See the attached detailed Office action for a list | reau (PCT Rule 17.2(a)). | | | | | |
| 14) Acknowledgment is made of a claim for domesti | ic priority under 35 U.S.C. § 119 | (e) (to a provisional application). | | | | |
| a) ☐ The translation of the foreign language pro 15)☐ Acknowledgment is made of a claim for domest | | | | | | |
| Attachment(s) | | | | | | |
| 1) Notice of References Cited (PTO-892) 2) Notice of Draftsperson's Patent Drawing Review (PTO-948) 3) Information Disclosure Statement(s) (PTO-1449) Paper No(s) | 5) Notice of Informal | ry (PTO-413) Paper No(s) I Patent Application (PTO-152) | | | | |
| C. Datast and Trademark Office | | | | | | |

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DETAILED ACTION

Acknowledgment

1. Acknowledgment is made that applicant's Amendment, filed on 05 February 2003, has been entered. Upon entrance of the Amendment, claims 1, 11 and 12 were amended and claim 10 was cancelled. Claims 1-9 and 11-12 are now pending in the current application.

2.

Specification

3. The lengthy specification has not been checked to the extent necessary to determine the presence of all possible minor errors. Applicant's cooperation is requested in correcting any errors of which applicant may become aware in the specification.

Claim Rejections - 35 USC § 102

4. The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

- (b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.
- (e) the invention was described in (1) an application for patent, published under section 122(b), by another filed in the United States before the invention by the applicant for patent or (2) a patent granted on an application for patent by another filed in the United States before the invention by the applicant for patent, except that an international application filed under the treaty defined in section 351(a) shall have the effects for purposes of this subsection of an application filed in the United States only if the international application designated the United States and was published under Article 21(2) of such treaty in the English language.

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5. Claims 1, 4-6 and 9 are rejected under 35 U.S.C. 102(b) as being anticipated by Kafka et al. (5365366). Kafka et al. discloses a laser apparatus FIG. 1 comprising a semiconductor laser element 28 which emits first laser light 34 having a first wavelength; a surface-emitting semiconductor element 20 which is excited with the first laser light 24, emits second laser light having a second wavelength which is longer than the first wavelength, and has an active layer 20 and a first mirror 14 arranged on one side of the active layer 20; a second mirror 16 which is arranged outside the surface-emitting semiconductor element 20 so that the first and second mirrors 14,16 form a resonator in which the second laser light resonates; and a modulation unit which modulates the surface-emitting semiconductor element 50, wherein the second mirror 16 is physically separated from the surface-emitting semiconductor element by an air gap, see col. 3, line 49-col. 6, line 55.

Regarding claims 4-5, Kafka et al. discloses a structure for controlling the spatial mode **108** and all the other stated limitations, **see col. 8, line 59-col. 10, line 15**.

Regarding claim 6, Kafka et al. discloses the first mirror has a limited area being arranged in parallel with a light-exit end surface of the surface-emitting semiconductor element, see FIG. 1.

Regarding claim 9, Kafka et al. discloses all the stated limitations, see FIG. 1.

6. Claims 1, 4-8 and 11 are rejected under 35 U.S.C. 102(e) as being anticipated by Caprara et al. (6097742). Caprara et al. discloses a laser apparatus **FIGS. 5 and 6** comprising a semiconductor laser element which emits first laser light **42** having a first wavelength; a surface-emitting semiconductor element **32** which is excited with the first

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laser light 42, emits second laser light having a second wavelength which is longer than the first wavelength, and has an active layer 34 and a first mirror 30 arranged on one side of the active layer 34; a second mirror 26 which is arranged outside the surface-emitting semiconductor element 32 so that the first and second mirrors 30,26 form a resonator in which the second laser light resonates; and a modulation unit which modulates the surface-emitting semiconductor element 82, wherein the second mirror 26 is physically separated from the surface-emitting semiconductor element by an air gap, see col. 6, line 33-col. 7, line 53 and col. 13, line 60-col 16, line 65.

Regarding claims 4-5, Caprara et al. discloses a structure for controlling the spatial mode **52** and all the other stated limitations, **see col. 9, line 66-col. 10, line 17**.

Regarding claims 6 and 7, Caprara et al. discloses the first mirror has a limited area being arranged in parallel with a light-exit end surface of the surface-emitting semiconductor element and all the other stated limitations, see FIGS. 5 and 6.

Regarding claims 8 and 11, Caprara et al. discloses all the stated limitations, **see**FIGS. 5 and 6.

7. Claims 1, 4-8 and 11 are rejected under 35 U.S.C. 102(e) as being anticipated by Raymond et al. (6097742). Raymond et al. discloses a laser apparatus **FIGS. 1 and 3** comprising a semiconductor laser element **100** which emits first laser light **102** having a first wavelength; a surface-emitting semiconductor element **10** which is excited with the first laser light **102**, emits second laser light **52** having a second wavelength which is longer than the first wavelength, and has an active layer **16** and a first mirror **14** arranged on one side of the active layer **16**; a second mirror **22** which is arranged

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outside the surface-emitting semiconductor element 10 so that the first and second mirrors 14,22 form a resonator in which the second laser light 52 resonates; and a modulation unit which modulates the surface-emitting semiconductor element see col. 7, lines 29-48, wherein the second mirror 22 is physically separated from the surface-emitting semiconductor element by an air gap, see col. 4, line 53-col. 6, line 51 and col. 8, lines 34-65.

Regarding claims 4 and 5, Raymond et al. discloses a structure for controlling the spatial mode **52** and all the other stated limitations, **see col. 7, lines 29-48**.

Regarding claims 6 and 7, Raymond et al. discloses the first mirror has a limited area being arranged in parallel with a light-exit end surface of the surface-emitting semiconductor element and all the other stated limitations, see FIGS. 1 and 3.

Regarding claims 8 and 11, Raymond et al. discloses all the stated limitations, see FIGS. 1 and 3.

Claim Rejections - 35 USC § 103

- 8. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
 - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 9. Claims 2-3 and 12-13 are rejected under 35 U.S.C. 103(a) as being unpatentable over Caprara et al. (6097742) or Raymond et al. (6097742) in view of Kurtz et al.

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(5995529) and/or Jayaraman (5513204). Caprara et al., as applied to claims 1, 4-8 and 11 above, and Raymond et al., as applied to claims 1, 4, 6-8 and 11 above, teaches all the stated limitations, see also Caprara et al. (FIG. 3 and col. 8, lines 39-67) or Raymond et al. (col. 2, lines 44-51 and col. 13, line 63-col. 14, line 12) except for the modulation unit modulates the surface-emitting semiconductor element by varying a voltage applied to the pn/Schottky junction. Kurtz et al. and Jayaraman teach that a modulation unit which modulates the surface-emitting semiconductor element by varying a voltage applied to the pn/Schottky junction of an optically pumped laser is well known in the art, see also Kurtz et al. (abstract and col. 1, lines 60-14) or Jayaraman (col. 4, lines 38-64 and claims 1-3 and 11-12). It has been held to be within the general skill of a worker in the art to select a known material on the basis of its suitability for the intended use as a matter of obvious design choice. *In re Leshin*, 125 USPQ 416.

Regarding claims 3 and 12-13, cited prior art discloses all the stated limitations, see the corresponding claim rejections above.

Response to Arguments

10. Applicant's arguments with respect to claims 1-13 have been considered but are most in view of the new ground(s) of rejection.

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Conclusion

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Cornelius H. Jackson whose telephone number is (703) 306-5981. The examiner can normally be reached on 8:00 - 5:00, Monday - Friday.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Paul Ip can be reached on (703) 308-3098. The fax phone numbers for the organization where this application or proceeding is assigned are (703)308-7722 for regular communications and (703)308-7721 for After Final communications.

Any inquiry of a general nature or relating to the status of this application or proceeding should be directed to the receptionist whose telephone number is (703)308-0956.

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May 4, 2003